

# Particle Size Control and Characteristics Analysis of Nanosized $\gamma$ -Alumina Powders

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Nanosized  $\text{Al}_2\text{O}_3$  particles were synthesized using the thermal CVD (Chemical Vapor Deposition) method.  $\text{AlCl}_3$  (Trichloroaluminum) was used as the starting material. The relationships between particle size and reaction temperature, and concentration and pressure were investigated. In the preparation of nanosized  $\text{Al}_2\text{O}_3$  particles, the typical  $\gamma$ - $\text{Al}_2\text{O}_3$  crystalline phases appeared above 1273 K. The particle size decreases from 8.2 nm to 3.7 nm with reaction pressure in the range of 101 kPa to 42.5 kPa. We obtained the smallest average particle size of 3.7 nm with geometric standard deviation of 0.8 nm. TEM observation shows that particles are spherical in shape. The size was also found to decrease from 8.9 nm to 6.1 nm when the reaction temperature was increased from 873 to 1273 K in an  $\text{AlCl}_3$  concentration of 0.014 mol%. The uniformity of  $\text{Al}_2\text{O}_3$  particles increased and decreased  $\text{AlCl}_3$  concentrations and reaction pressures. [Received August 6, 2003; Accepted December 19, 2003]

**Key-words :**  $\text{Al}_2\text{O}_3$ , Thermal CVD method,  $\text{AlCl}_3$  (Trichloroaluminum)

## 1. Introduction

Nanosized powders have drawn considerable attention as raw materials of electrical parts and structural ceramics. Nanoscale particles of less than  $0.01 \mu\text{m}$  in size have the unique properties of low sintering temperature and high activity catalysis.<sup>1)-4)</sup> Nanoscale particles can be fabricated using the thermal evaporated condensation method by plasma or induction heater, laser ablation method, chemical vapor deposition (CVD) method, spray pyrolysis method, Sol-Gel method and milling process.<sup>5)-7)</sup> Recently, these manufacturing processes have been studied intensively to obtain the optimum manufacturing conditions and the synthesizing kinetics of nanosized powders. Among these processes, the CVD method is one of the most promising candidates due to the possibility of mass production of very pure nanosized powders with good size uniformity. In the CVD process, it has generally been recognized that the particle size is affected by various processing factors such as reaction temperature, gas species, pressure and precursor concentration. However, the influence of these factors on the synthesis has not yet been verified.

In this study, high purity nanosized  $\gamma$ - $\text{Al}_2\text{O}_3$  particles with homogeneous uniformity were synthesized using the thermal CVD method. The optimum conditions were obtained by varying the reaction parameters, i.e. reaction temperature, concentration and pressure. The size, shape and phase of the  $\gamma$ - $\text{Al}_2\text{O}_3$  particles were investigated under their various reaction conditions.

## 2. Experimental method

The nanosized  $\gamma$ - $\text{Al}_2\text{O}_3$  particles were prepared using the tube type thermal CVD system, which consisted of an evaporator, thermal reactor, filter and vacuum pump. Figure 1 shows the schematic diagram of the thermal CVD system used in this experiment.  $\text{AlCl}_3$  (Trichloroaluminum, TCA) as a raw material was evaporated in the evaporator and then carried into the reactor by He gas at a flow rate of  $8.33 \times 10^{-7} \text{ m}^3/\text{sec}$ . The TCA concentration was changed from 0.014 mol% to 0.078 mol% by controlling the evaporation temperature under He atmosphere. Furthermore, a reactant gas such as  $\text{H}_2\text{O} + \text{O}_2$  was delivered into the thermal reactor in order to react with the TCA. The flow rate of  $\text{H}_2\text{O} + \text{O}_2$  gas was  $1.66 \times 10^{-5} \text{ m}^3/\text{sec}$ . The reaction conditions were varied from 873 to 1273 K in temperature and from 42.5 kPa to 101 kPa in pressure. The

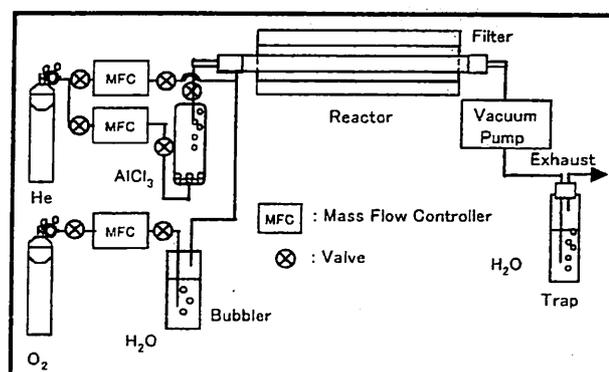


Fig. 1. Schematic diagram of the thermal CVD system.

synthesized  $\gamma$ - $\text{Al}_2\text{O}_3$  particles were collected in the attached micro-filters. The crystalline phases were identified by X-ray diffraction (XRD, RIGAKU RINT-2500) analysis using  $\text{CuK}\alpha$  radiation. The particle morphologies and size were examined by transmission electron microscopy (TEM, HITACHI H-800) observation.

## 3. Results and discussion

The phase change of synthesized  $\text{Al}_2\text{O}_3$  particles showed dependence on reaction temperature. Figure 2 shows X-ray diffraction patterns of  $\text{Al}_2\text{O}_3$  particles for various reaction temperatures. The reaction temperature range was from 873 to 1273 K, and the TCA concentration was 0.014 mol%. XRD analysis shows that the crystalline phase of the particles was amorphous below 1173 K at atmospheric pressure. The typical  $\gamma$ - $\text{Al}_2\text{O}_3$  crystalline phases appeared at the reaction temperature above 1273 K. Figure 3 shows a TEM micrograph of nanosized  $\gamma$ - $\text{Al}_2\text{O}_3$  powders synthesized at a reaction temperature of 1273 K. At that time, the TCA concentration was 0.014 mol%. The synthesized particles were spherical in shape. The average size was obtained by a logarithmic normal distribution method. The average particle size was 6.1 nm and geometric standard deviation was 1.1 nm. Figure 4 shows the change in average  $\gamma$ - $\text{Al}_2\text{O}_3$  particle size as a function of reaction temperatures and TCA concentrations. When the reaction tempera-

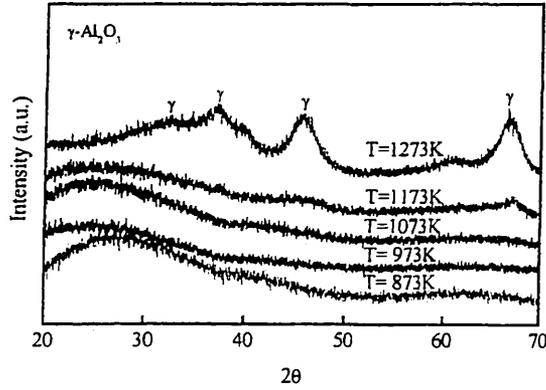


Fig. 2. The X-ray diffraction pattern of Al<sub>2</sub>O<sub>3</sub> particles depends on reaction temperatures at a TCA concentration of 0.014 (mol%).

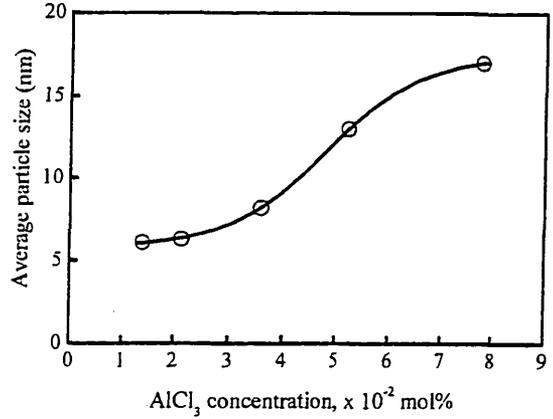


Fig. 5. Al<sub>2</sub>O<sub>3</sub> average particle size as a function of TCA concentrations (mol%) at 1273 K.

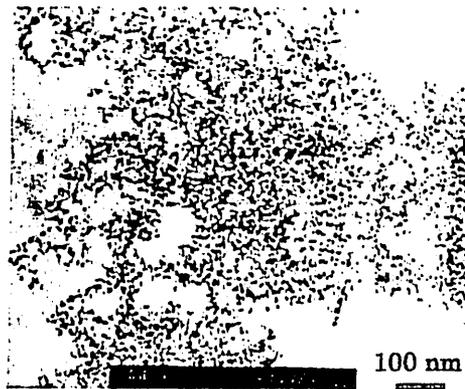


Fig. 3. TEM micrograph of  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> synthesized at a reaction temperature of 1273 K and TCA concentration of 0.014 mol%.

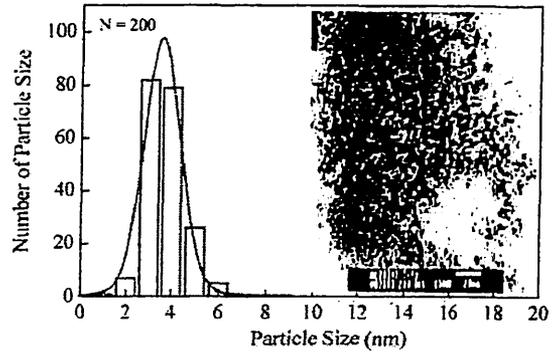


Fig. 6. The size distribution and TEM micrograph of Al<sub>2</sub>O<sub>3</sub> particles synthesized at TCA concentration of 0.036 mol% and reaction pressure of 42.5 kPa.

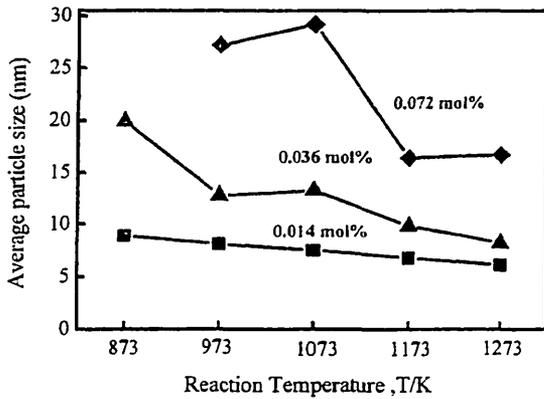


Fig. 4. Change of  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> average particle size as a function of reaction temperatures and TCA concentrations.

ture was increased from 873 to 1273 K at 0.014 mol%, the  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> particle size decreased from 8.9 nm to 6.1 nm. The Al<sub>2</sub>O<sub>3</sub> particle size also decreases with decreasing TCA concentration.

The dependence of average  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> particle size on TCA concentration is shown in Fig. 5. The synthesizing temperature was 1273 K and TCA concentrations were changed from 0.014 to 0.078 mol%. In a TCA concentration of 0.014 mol%, the smallest average particle size (6.1 nm) was obtained. The

average particle size decreased with decreasing TCA concentration. Moreover, it was observed that the particle size distributions have a narrow band with decreasing TCA concentration. The geometric standard deviation changed from 3.6 to 1.1 nm.

Figure 6 shows the size distribution and TEM micrograph of  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> particles synthesized at a TCA concentration of 0.036 mol% and reaction pressure of 42.5 kPa. It shows that the average  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> particle size and a geometric standard deviation are 3.7 nm and 0.8 nm, respectively.  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> particles synthesized under these conditions were obtained with high homogeneous uniformity. The dependence of average size of the  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> particles synthesized at 0.036 mol% at various pressures is shown in Fig. 7. In this study, the smallest average particle size of 3.7 nm was obtained at reaction pressure of 42.5 kPa. The particle size decreased from 8.2 to 3.7 nm with decreasing reaction pressures and the geometric standard deviation changed from 1.9 to 0.8 nm. The average size of  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> particles synthesized at 42.5 kPa was almost half of that at 101 kPa.

Nucleation of  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> powder occurred at the entrance of the reactor when the precursor was formed from the reaction between TCA and the reactant gas. The nuclei grow into particles when passed through the reactor. The particle size was determined by the number of nuclei in unit volume and the precursor concentration. It was observed that the number of nuclei existed in unit volume as the reaction decreases for

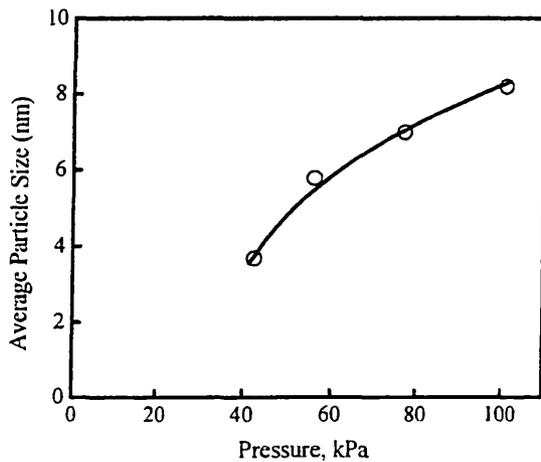


Fig. 7. The average particle size change of  $\gamma$ - $\text{Al}_2\text{O}_3$  powders synthesized at 0.036 mol% based on various pressure levels.

decreasing reaction temperature. From the above results, the nucleation occurred for a longer time than that performed at high temperature. As a result, the geometric standard deviation increased at low temperatures. When the same nucleus existed, concentration and pressure influence the particle size and the geometric standard deviation. At low concentration or low pressure, the nuclei have a few opportunities for collision within the precursor. Therefore, the particle size becomes

smaller compared the case of high concentration or high pressure.

#### 4. Conclusions

The effects of reaction temperatures, TCA concentrations, and pressures on the average particle size of nanosized  $\gamma$ - $\text{Al}_2\text{O}_3$  powders were investigated. The average particle size of the powders decreased when increasing the reaction temperature and decreasing the TCA concentrations or pressure levels. In the prepared nanosized  $\text{Al}_2\text{O}_3$  particles, typical  $\gamma$ - $\text{Al}_2\text{O}_3$  crystalline phases appeared above 1273 K. We obtained the smallest average particle size of 3.7 nm with geometric standard deviation of 0.8 nm.

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